

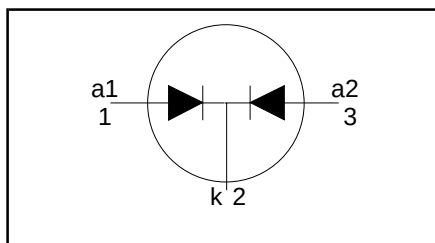
Rectifier diodes Schottky barrier

PBYR2545CTF, PBYR2545CTX

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

$$V_R = 40 \text{ V} / 45 \text{ V}$$

$$I_{O(AV)} = 20 \text{ A}$$

$$V_F \leq 0.65 \text{ V}$$

GENERAL DESCRIPTION

Dual, common cathode schottky rectifier diodes in a plastic envelope with electrically isolated mounting tab. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

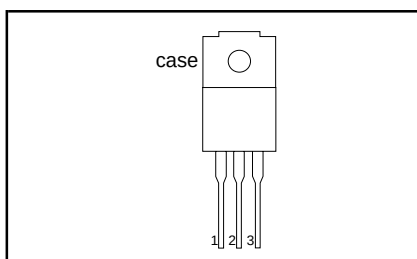
The PBYR2545CTF is supplied in the SOT186 package.

The PBYR2545CTX is supplied in the SOT186A package.

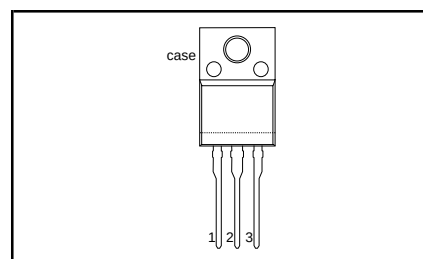
PINNING

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)
tab	isolated

SOT186



SOT186A



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
		PBYR25 PBYR25		40CTF 40CTX	45CTF 45CTX	
V_{RRM}	Peak repetitive reverse voltage		-	40	45	V
V_{RWM}	Working peak reverse voltage		-	40	45	V
V_R	Continuous reverse voltage	$T_{hs} \leq 86^\circ\text{C}$	-	40	45	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting)	square wave; $\delta = 0.5$; $T_{hs} \leq 98^\circ\text{C}$	-	20		A
I_{FRM}	Repetitive peak forward current per diode	square wave; $\delta = 0.5$; $T_{hs} \leq 98^\circ\text{C}$	-	20		A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10 \text{ ms}$	-	135		A
		$t = 8.3 \text{ ms}$	-	150		A
I_{RRM}	Peak repetitive reverse surge current per diode	sinusoidal; $T_j = 125^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by T_{jmax}	-	1		A
T_j	Operating junction temperature		-	150		$^\circ\text{C}$
T_{stg}	Storage temperature		- 65	175		$^\circ\text{C}$

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	Peak isolation voltage from all terminals to external heatsink	SOT186 package; R.H. $\leq 65\%$; clean and dustfree	-	-	1500	V
V_{isol}	R.M.S. isolation voltage from all terminals to external heatsink	SOT186A package; $f = 50\text{-}60\text{ Hz}$; sinusoidal waveform; R.H. $\leq 65\%$; clean and dustfree	-	-	2500	V
C_{isol}	Capacitance from pin 2 to external heatsink	$f = 1\text{ MHz}$	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j\text{-}hs}$	Thermal resistance junction to heatsink	per diode both diodes (with heatsink compound)	-	-	4.8 4	K/W K/W
$R_{th\ j\text{-}a}$	Thermal resistance junction to ambient	in free air	-	55	-	K/W

ELECTRICAL CHARACTERISTICS

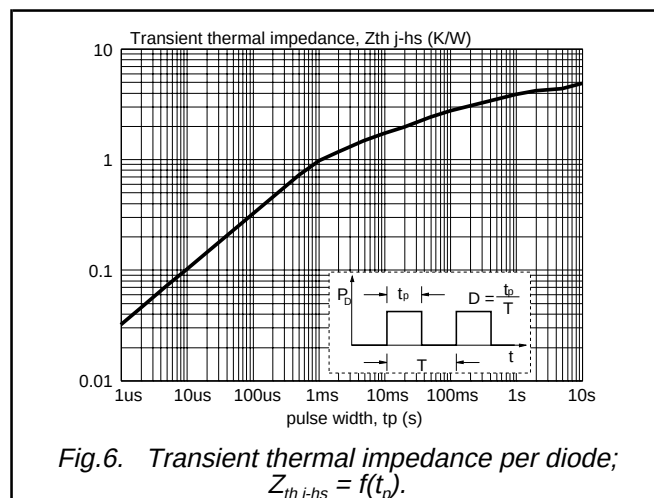
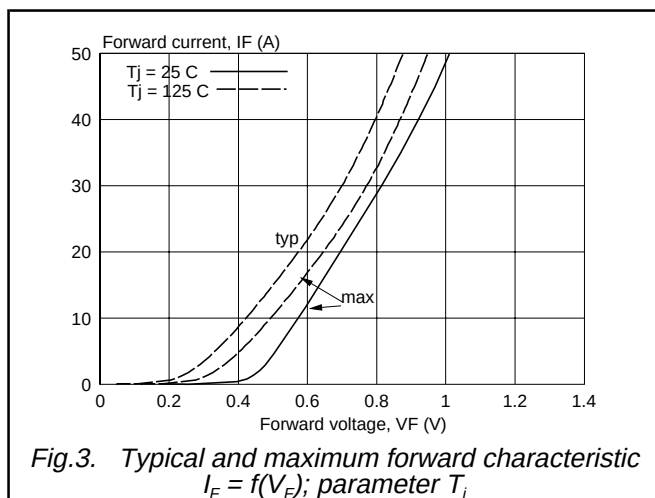
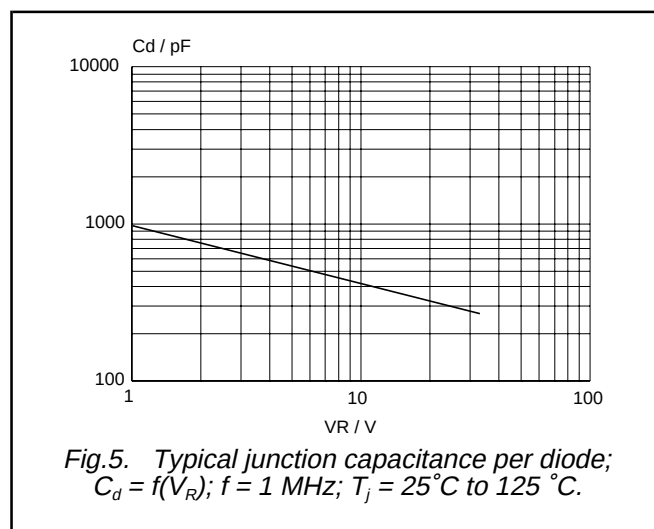
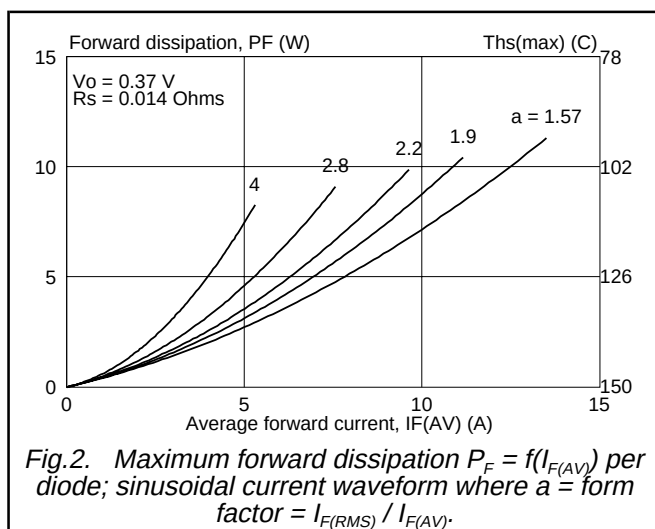
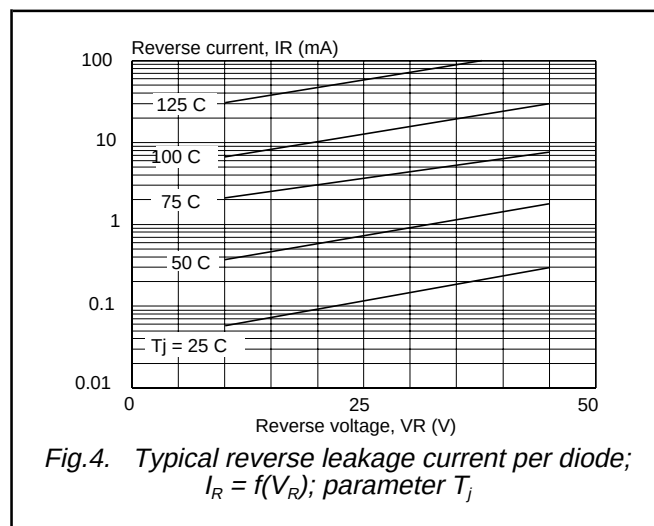
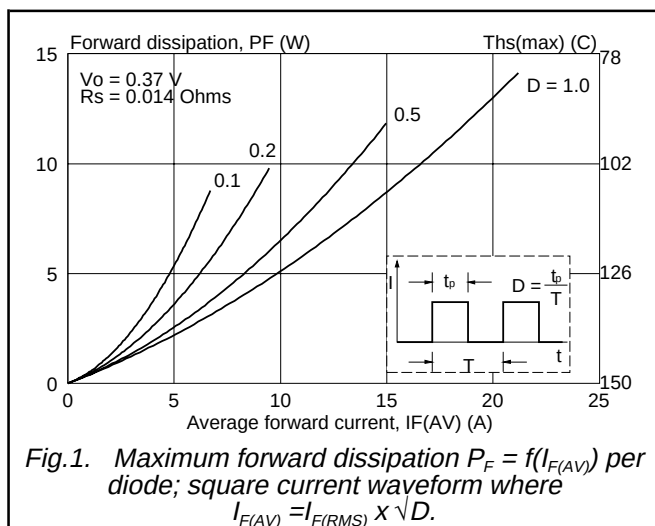
 $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage per diode	$I_F = 20\text{ A}$; $T_j = 125\text{ }^{\circ}\text{C}$	-	0.58	0.65	V
I_R	Reverse current per diode	$I_F = 20\text{ A}$ $V_R = V_{RWM}$	-	0.63	0.68	V
		$V_R = V_{RWM}$; $T_j = 100\text{ }^{\circ}\text{C}$	-	0.3	2	mA
C_d	Junction capacitance per diode	$V_R = 5\text{ V}$; $f = 1\text{ MHz}$; $T_j = 25\text{ }^{\circ}\text{C}$ to $125\text{ }^{\circ}\text{C}$	-	30 530	40 -	mA pF

Rectifier diodes

Schottky barrier

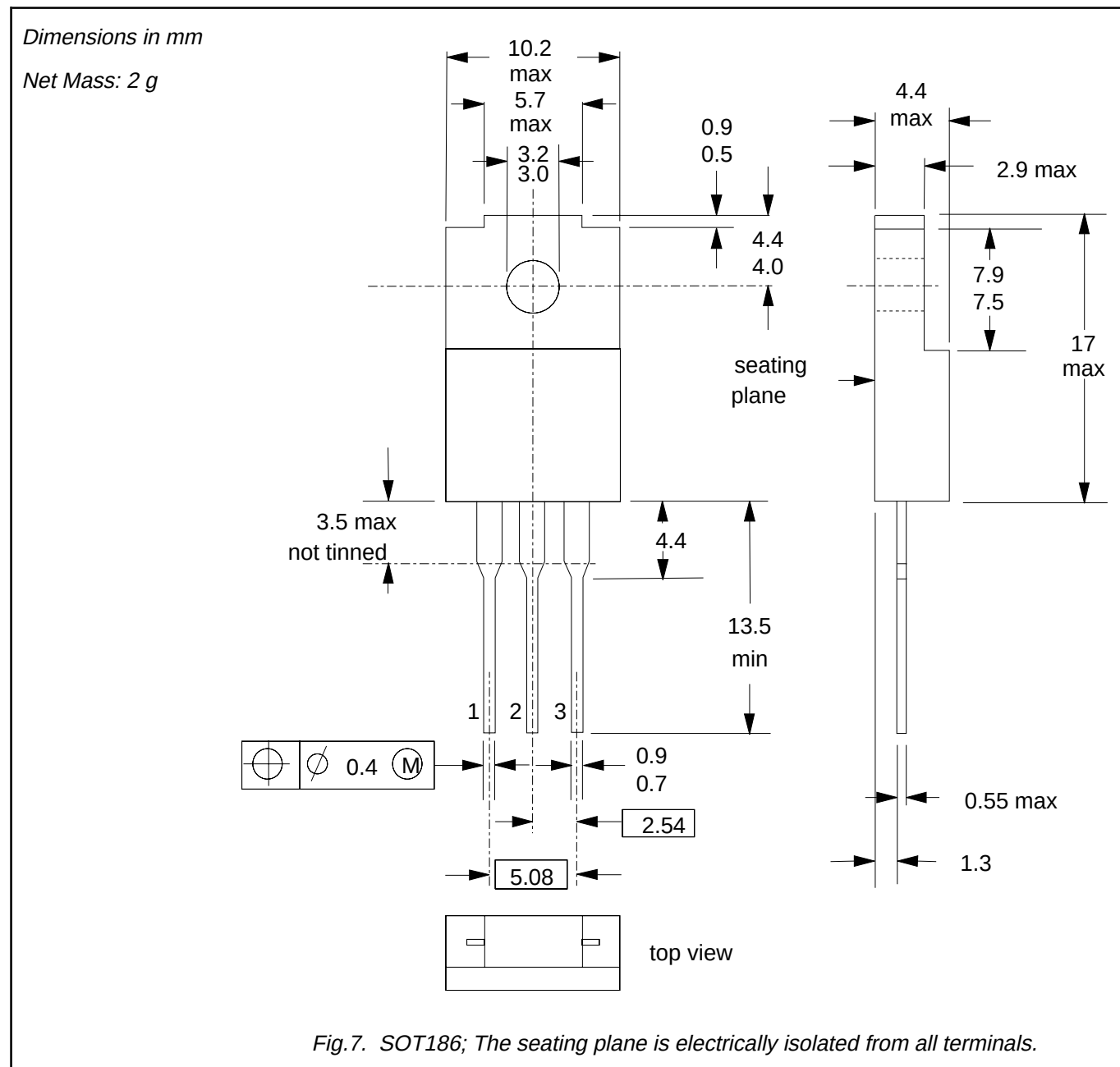
PBYR2545CTF, PBYR2545CTX



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MECHANICAL DATA



Notes

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

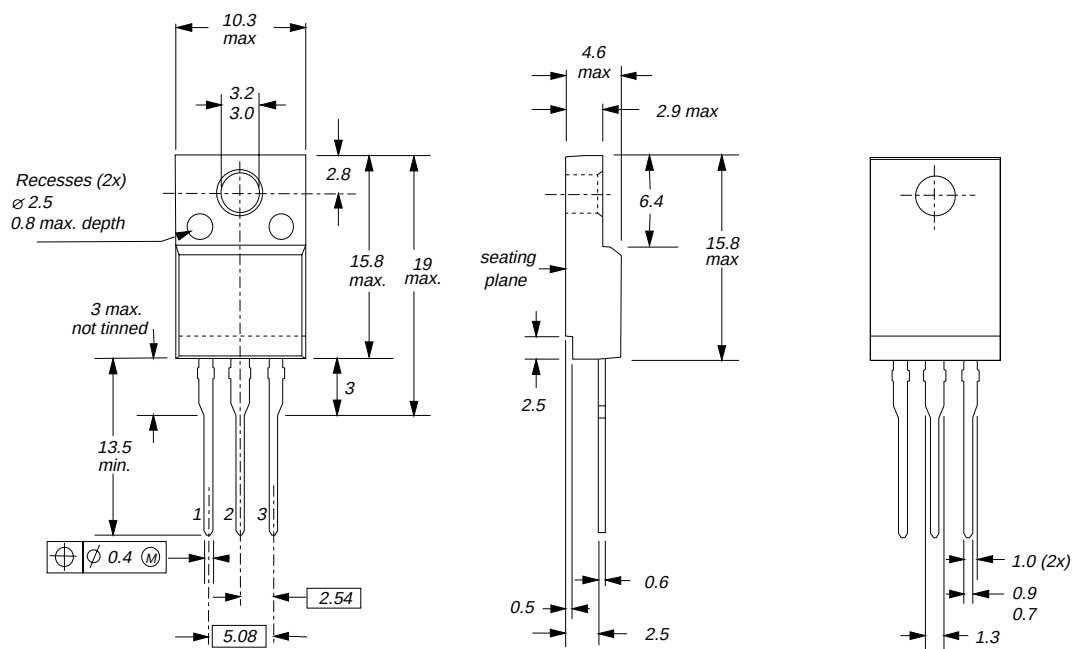


Fig.8. SOT186A; The seating plane is electrically isolated from all terminals.

Notes

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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